

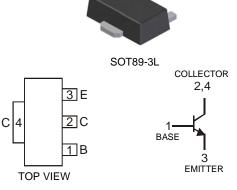


XT5551

NPN SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (DXT5401)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- **Mechanical Data**
- Case: SOT89-3L •
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper Leadframe . (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	lc	600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation $@T_A = 25^{\circ}C$ (Note 3)	PD	1	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$ (Note 3)	$R_{ ext{ heta}JA}$	125	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	O°

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	180		V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	160		V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cutoff Current	Ісво		50	nA	$V_{CB} = 120V, I_E = 0$
	ICBO		50	μΑ	$V_{CB} = 120V, I_E = 0, T_A = 100^{\circ}C$
Emitter Cutoff Current	I _{EBO}		50	nA	$V_{EB} = 4.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)					
		80			$V_{CE} = 5.0V, I_{C} = 1.0mA$
DC Current Gain	h _{FE}	80	250	—	$V_{CE} = 5.0V, I_{C} = 10mA$
		30			$V_{CE} = 5.0V, I_C = 50mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.15 0.20	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 1.0 {\rm mA}$
Collector-Enlitter Saturation Voltage				v	$I_{C} = 50 \text{mA}, I_{B} = 5.0 \text{mA}$
Page Emitter Seturation Voltage	N/	_	1.0	V	$I_{C} = 10mA, I_{B} = 1.0mA$
Base-Emitter Saturation Voltage	VBE(SAT)				$I_{C} = 50 \text{mA}, I_{B} = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					·
Output Capacitance	C _{obo}	—	6.0	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$
Small Signal Current Gain	h _{fe}	50	200	_	V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f _T	100	300	MHz	V _{CE} = 10V, I _C = 10mA, f = 100MHz
Noise Figure	NF		8.0	dB	$V_{CE} = 5.0V$, $I_C = 200\mu A$, $R_S = 1.0k\Omega$, $f = 1.0kHz$

1. No purposefully added lead.

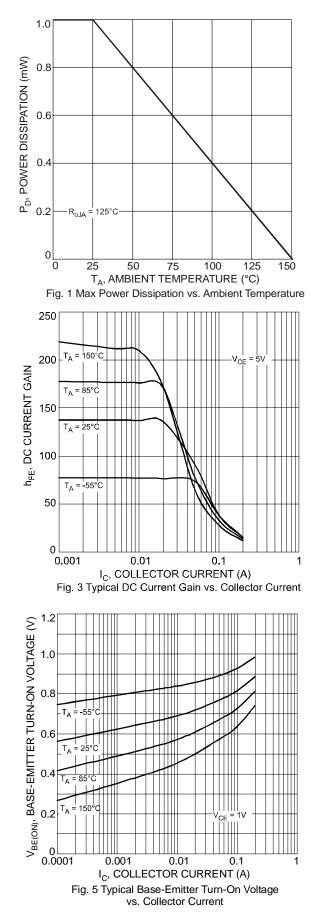
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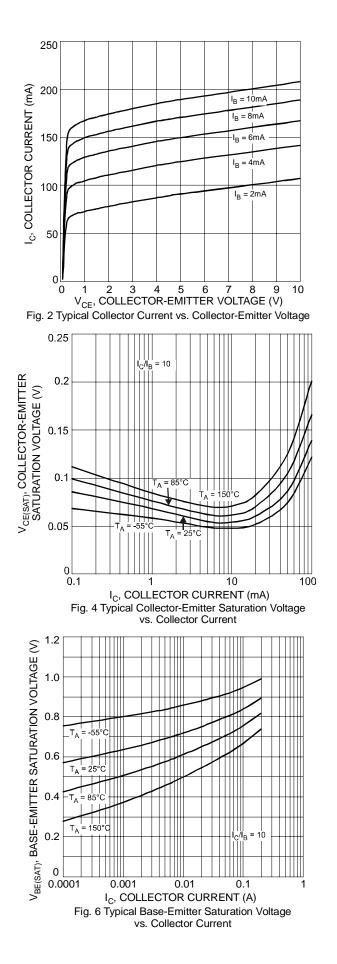
Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our 3. website at http://www.diodes.com/datasheets/ap02001.pdf.

4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

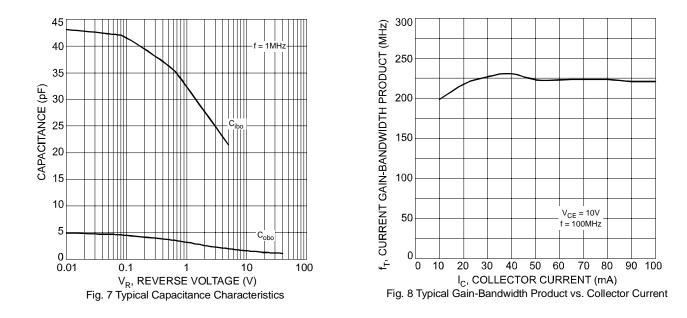
Notes:









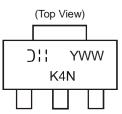


Ordering Information (Note 5)

Device	Packaging	Shipping
DXT5551-13	SOT89-3L	2500/Tape & Reel

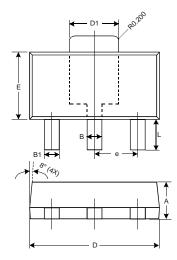
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

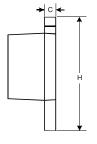
Marking Information



>II = Manufacturer's code marking
K4N = Product type marking code
YWW = Date code marking
Y = Last digit of year ex: 7 = 2007
WW = Week code 01 - 52

Package Outline Dimensions

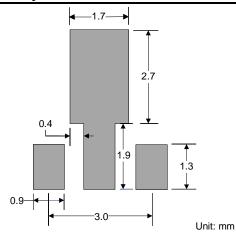




SOT89-3L				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
В	0.45	0.55	0.50	
B1	0.37	0.47	0.42	
С	0.35	0.43	0.38	
D	4.40	4.60	4.50	
D1	1.50	1.70	1.60	
ш	2.40	2.60	2.50	
e	_	_	1.50	
Н	3.95	4.25	4.10	
L	0.90	1.20	1.05	
All Dimensions in mm				



Suggested Pad Layout



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